



N-Channel 2.5-V (G-S) MOSFET

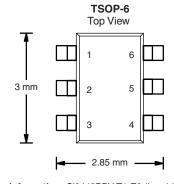
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$				
20	0.057 at V _{GS} = 4.5 V	4.2			
	0.090 at V _{GS} = 2.5 V	3.4			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC



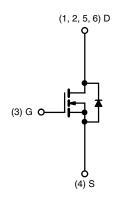




Ordering Information: Si3442BDV-T1-E3 (Lead (Pb)-free)

Si3442BDV-T1-GE3 (Lead (Pb)-free and Halogen-free)

Marking Code: 2Bxxx



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	20		٧	
Gate-Source Voltage		V _{GS}	± 12			
Continuous Drain Current /T 150 °C\8	T _A = 25 °C	- I _D	4.2	3.0		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		3.4	2.4		
Pulsed Drain Current		I _{DM}	20		А	
Continuous Source Current (Diode Conduction) ^a	I _S	1.4	0.72			
Mariana Barra Biratanting	T _A = 25 °C	P _D	1.67	0.86	W	
Maximum Power Dissipation ^a	T _A = 70 °C	l 'D	1.07	0.55	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Mariana baratian ta Ambianta	t ≤ 5 s	R _{thJA}	75	100]
Maximum Junction-to-Ambient ^a	Steady State	' ¹thJA	120	145	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	70	85	

Note:

a. Surface Mounted on FR4 board, $t \le 5 \ s.$

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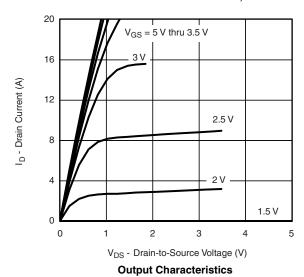
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static				•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6		1.8	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA	
Zana Cata Valtana Busin Comment		V _{DS} = 20 V, V _{GS} = 0 V			1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			5		
0.00.1.00.13	1	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	10			^	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 2.5 \text{ V}$	4			A	
	В	V _{GS} = 4.5 V, I _D = 4 A		0.045	0.057	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 3.4 \text{ A}$		0.070	0.090		
Forward Transconductance ^a	g _{fs}	$V_{DS} = 10 \text{ V}, I_{D} = 4.0 \text{ A}$		11.3		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1.6 A, V _{GS} = 0 V		0.75	1.2	V	
Dynamic ^b							
Input Capacitance	C _{iss}			295		pF	
Output Capacitance	C _{oss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		75			
Reverse Transfer Capacitance	C _{rss}			45			
Total Gate Charge	Q_g			3	5		
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 4.0 \text{ A}$		0.65		nC	
Gate-Drain Charge	Q_{gd}			0.95			
Gate Resistance	R_g	f = 1 MHz		2.7		Ω	
Turn-On Delay Time	t _{d(on)}			35	55		
Rise Time	t _r	V_{DD} = 10 V, R_L = 10 Ω		50	75	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong 1$ A, V_{GEN} = 4.5 V, R_g = 6 Ω		20	30		
Fall Time	t _f			15	25		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.6 A, dI/dt = 100 A/μs		30	60		

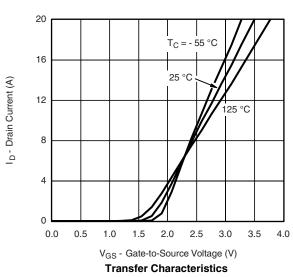
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



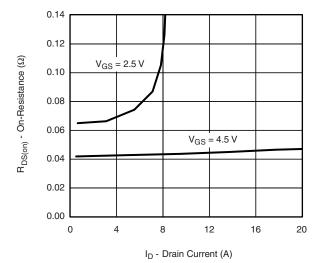




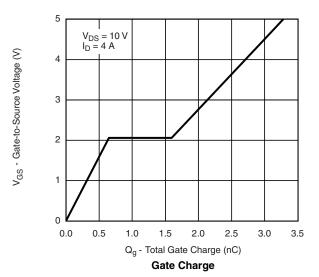


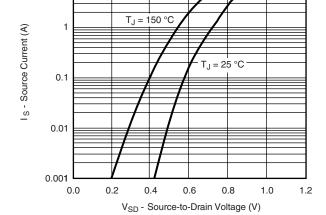


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



On-Resistance vs. Drain Current



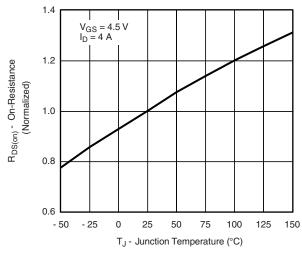


Source-Drain Diode Forward Voltage

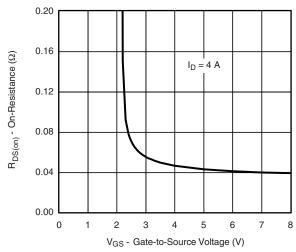
480 400 400 240 240 Coss Coss Coss 0 0 4 8 12 16 20

V_{DS} - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature



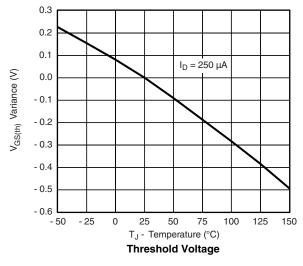
On-Resistance vs. Gate-to-Source Voltage

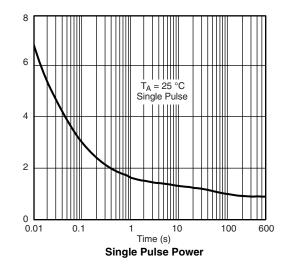
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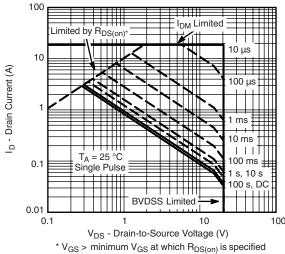
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



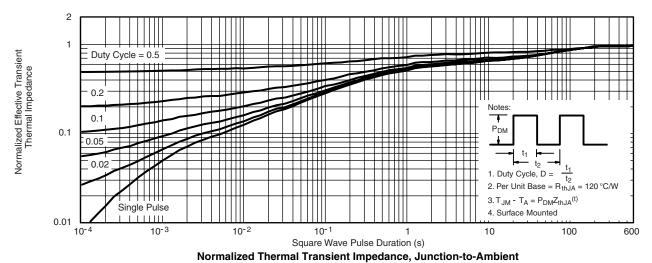




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Power

Safe Operating Area



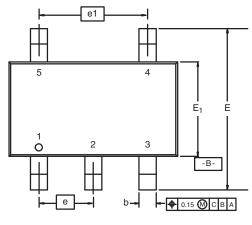
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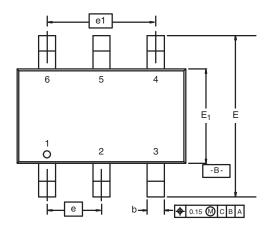




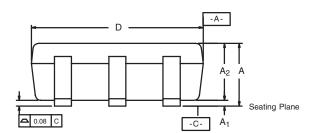
TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C

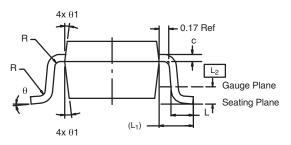




5-LEAD TSOP





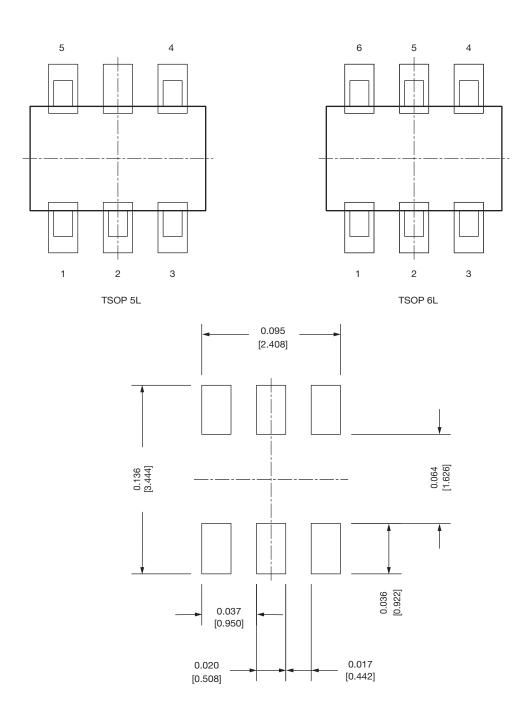


	MILLIMETERS			INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
E	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е	0.95 BSC			0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071 0.075 (0.079	
L	0.32	-	0.50	0.012	-	0.020	
L ₁	0.60 Ref			0.024 Ref			
L ₂	0.25 BSC			0.010 BSC			
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1		7° Nom		7° Nom			
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

Document Number: 71200 18-Dec-06



Recommended Land Pattern For TSOP-5L / TSOP-6L



Note

• All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022 DWG: 3010



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